Coexistence of Massless and Massive Dirac Fermions in Topological Crystalline Insulators

Ilija Zeljkovic¹, Yoshinori Okada^{1,2}, Cheng-Yi Huang³, R. Sankar⁴, Daniel Walkup¹, Wenwen Zhou¹, Maksym Serbyn⁵, Fangcheng Chou⁴, Wei-Feng Tsai³, Hsin Lin⁶, A. Bansil⁷, Liang Fu⁵, M. Zahid Hasan⁸ and Vidya Madhavan¹

¹Department of Physics, Boston College, Chestnut Hill, Massachusetts 02467, USA ²WPI-AIMR, Tohoku University, Sendai, 980-8577, Japan

³Department of Physics, National Sun Yat-sen University, Kaohsiung 80424, Taiwan

⁴Center for Condensed Matter Sciences, National Taiwan University, Taipei 10617, Taiwan

⁵Department of Physics, Massachusetts Institute of Technology, Cambridge, MA 02139,USA

⁶Graphene Research Centre and Department of Physics, National University of Singapore, Singapore 117542

⁷Department of Physics, Northeastern University, Boston, Massachusetts 02115, USA

⁸Joseph Henry Laboratory, Department of Physics, Princeton University, Princeton, New Jersey 08544, USA

Topological crystalline insulators are recently discovered topological materials [1,2] where topology and crystal symmetry intertwine to create massless electrons, which behave like relativistic particles. Among the theoretical predictions for topological crystalline insulators is the possibility of imparting mass to these massless Dirac fermions by breaking crystal symmetry. In this talk I will discuss our recent experimental and theoretical investigations of a topological crystalline insulators, $Pb_{1-x}Sn_xSe$ [3]. We performed scanning tunneling microscopy (STM) studies at low temperatures and as a function of magnetic field. By analyzing two types of STM data: Fourier transforms of interference patterns and Landau level spectroscopy, we reveal the coexistence of zero mass Dirac fermions protected by crystal symmetry with massive Dirac fermions resulting from crystal symmetry breaking. In addition, I will discuss our recent data on the evolution of the mass as well as the Dirac surface states as we go through a quantum phase transition from the topological to trivial regime.

[1] L. Fu, Topological Crystalline Insulators, Phys. Rev. Lett. 106, 106802 (2011).

[2] T. H. Hsieh et al., Topological crystalline insulators in the SnTe material class, *Nat. Commun.* **3**, 982 (2012).

[3] Y. Okada, et.al., Observation of Dirac node formation and mass acquisition in a topological crystalline insulator, *Science* **341**, 1496-1499 (2013).